

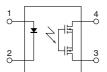
Panasonic ideas for life

Super miniature design, SOP(1 Form A) 4-pin type Controls load voltage 60V, 350V, 400V

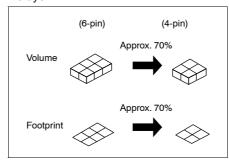
GU PhotoMOS (AQY21OS)



mm inch



The device comes in a super-miniature SO package 4-Pin type measuring (W)4.3 \times (L)4.4 \times (H)2.1 mm (W).169 \times (L).173 \times (H).083 inch —approx. 70% of the volume and 70% of the footprint size of SO package 6-pin type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

3. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current In contrast to the SSR with an off state leakage current of several milliamperes, the PhotoMOS relay features a very small off state leakage current of typ. 100 pA (AQY214S) even with the rated load voltage of 400 V.

TYPICAL APPLICATIONS

- Telecommunications (PC, Electronic Notepad)
- Measuring and Testing equipment
- Factory Automation Equipment
- Security equipment
- High speed inspection machines

FEATURES

1. SO package 4-Pin type in super miniature design

TYPES

Туре	Output rating*		Package		Part No.	Packing quantity		
	Load voltage	Load current	size	Tube packing style	Tape and reel	packing style	Tube	Tape and reel
AC/DC type	60V	500mA		AQY212S	AQY212SX (Picked from the 1/2-pin side)	AQY212SZ (Picked from the 3/4-pin side)		1,000 pcs.
	350V	120mA	SOP4pin	AQY210S	AQY210SX (Picked from the 1/2-pin side)	AQY210SZ (Picked from the 3/4-pin side)	1 tube contains: 100 pcs. 1 batch contains: 2,000 pcs.	
	400V	100mA		AQY214S	AQY214SX (Picked from the 1/2-pin side)	AQY214SZ (Picked from the 3/4-pin side)	2,000 μcs.	

^{*} Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the SMD terminal shape indicator "S" and the packaging style indicator "X" or "Z" are not marked on the relay. (Ex. the label for product number AQY210S is 210)

RATING

AC/DC type

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY212S	AQY210S	AQY214S	Remarks
	LED forward current	I F	50 mA			
Input	LED reverse voltage	VR	5 V			
	Peak forward current	I FP	1 A		f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin	75 mW			
	Load voltage (peak AC)	VL	60 V	350 V	400 V	
Output	Continuous load current (peak AC)	IL	0.5 A	0.12 A	0.1 A	
Output	Peak load current	Ipeak	1.5 A	0.3 A	0.24 A	100ms (1 shot), V _L = DC
	Power dissipation	Pout	300 mW			
Total power dissipation		Р⊤	350 mW			
I/O isolation voltage		Viso	1,500 V AC			
Temperature limits	Operating	Topr	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
	Storage T _{stg} -40°C to +100°C -40°			+100°C -40°F t	:o +212°F	

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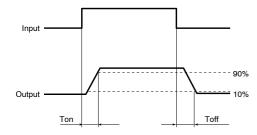
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQY212S	AQY210S	AQY214S	Remarks	
Input	LED approte current	Typical	I Fon	0.9 mA			IL = Max.
	LED operate current	Maximum					
	LED turn off current	Minimum	1	0.4 mA			I∟ = Max.
	LED turn on current	Typical	Foff	0.85 mA			
	LED dropout voltage	Typical	VF	1.25 V (1.14 V at I _F = 5 mA)			I _F = 50 mA
	LED dropout voltage	Maximum	VF	1.5 V			
	On resistance	Typical	Ron	$0.83~\Omega$	17 Ω	25 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
Output		Maximum		$2.5~\Omega$	25 Ω	35 Ω	
	Off state leakage current	Maximum	Leak	1 μΑ			I _F = 0 mA V _L = Max.
	Turn on time*	Typical	Ton	0.65 ms	0.23 ms	0.21 ms	I _F = 5 mA I _L = Max.
		Maximum		2 ms	0.5 ms	0.5 ms	
Transfer	Turn off time*	Typical	Toff	0.04 ms			I _F = 5 mA I _L = Max.
Transfer characteristics	rum on time	Maximum	I off	0.2 ms			
	I/O capacitance Maximum		Ciso	1.5 pF			f = 1 MHz V _B = 0 V
	Initial I/O isolation resistance	Minimum	Riso	1,000 ΜΩ			500 V DC

Note: Recommendable LED forward current IF = 5mA.

Type of connection

*Turn on/Turn off time

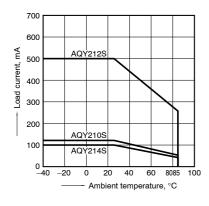


- **Dimensions**
- **Schematic and Wiring Diagrams**
- **■** Cautions for Use

REFERENCE DATA

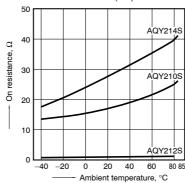
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



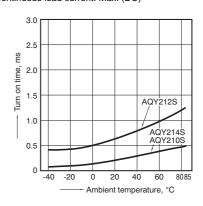
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

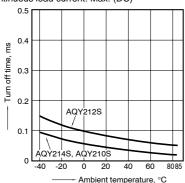
LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



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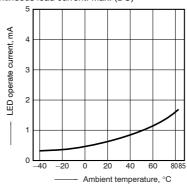
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



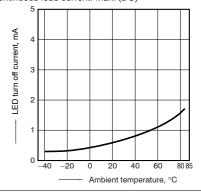
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



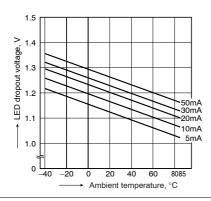
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



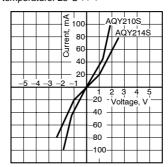
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



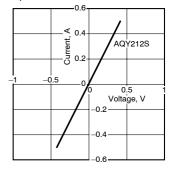
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C $77^{\circ}F$



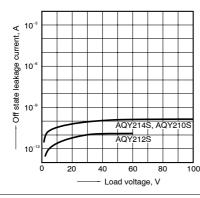
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



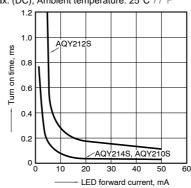
Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



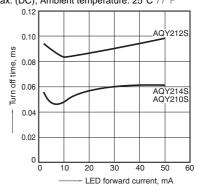
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25° C 77° F



11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;

